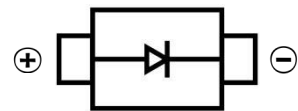


**SCHOTTKY BARRIER DIODE**
**FEATURES**

- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low forward voltage drop
- Designed and qualified for industrial level
- Surface Mount device


**SMA**
**MECHANICAL DATA**

- Case: SMA(DO-214AC)
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.065 grams (approximate)



<b>MAJOR RATINGS AND CHARACTERISTICS</b>			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	DC	1	A
$V_{RRM}$		100	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	120	A
$V_F$	1.5 Apk, $T_J = 125^\circ C$	0.68	V
$T_J$	Range	- 55 to 150	$^\circ C$

<b>VOLTAGE RATINGS</b>			
PARAMETER	SYMBOL	10MQ100	UNITS
Maximum DC reverse voltage	$V_R$	100	V
Maximum working peak reverse voltage	$V_{RWM}$		

<b>ABSOLUTE MAXIMUM RATINGS</b>				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 4	$I_{F(AV)}$	50 % duty cycle at $T_L = 126^\circ C$ , rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)	1.5	A
		50 % duty cycle at $T_L = 135^\circ C$ , rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)	1	
Maximum peak one cycle non-repetitive surge current, $T_J = 25^\circ C$ See fig. 6	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	120
		10 ms sine or 6 ms rect. pulse		30
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25^\circ C$ , $I_{AS} = 0.5 A$ , $L = 8 mH$	1.0	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	0.5	A

**SCHOTTKY BARRIER DIODE**

<b>ELECTRICAL SPECIFICATIONS</b>					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^\circ\text{C}$	0.78	V
		1.5 A		0.85	
		1 A	$T_J = 125\text{ }^\circ\text{C}$	0.63	
		1.5 A		0.68	
Maximum reverse leakage current See fig. 2	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	0.1	mA
		$T_J = 125\text{ }^\circ\text{C}$		1	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.52	V
Forward slope resistance	$r_t$			78.4	m $\Omega$
Typical junction capacitance	$C_T$	$V_R = 10\text{ V}_{DC}$ , $T_J = 25\text{ }^\circ\text{C}$ , test signal = 1 MHz		38	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu$ s

**Note**

(1) Pulse width = 300  $\mu$ s, duty cycle = 2 %

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}$ , $T_{Stg}$			- 55 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$	DC operation		80	$^\circ\text{C}/\text{W}$
Approximate weight				0.07	g
				0.002	oz.
Marking device		Case style SMA (similar D-64)		1J	

**Note**

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

SCHOTTKY BARRIER DIODE

Typical Characteristics

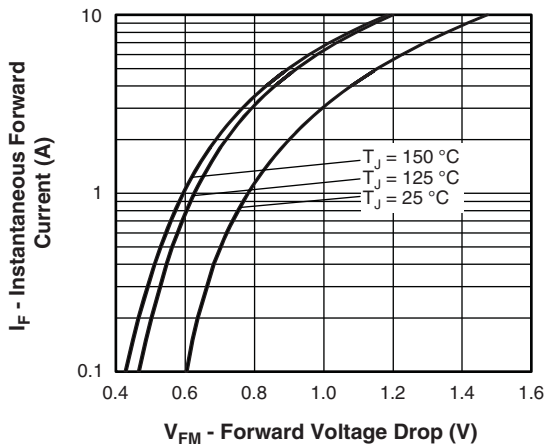


Fig. 1 - Maximum Forward Voltage Drop Characteristics

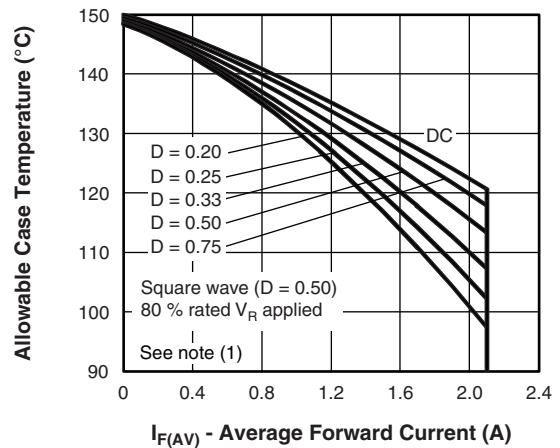


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

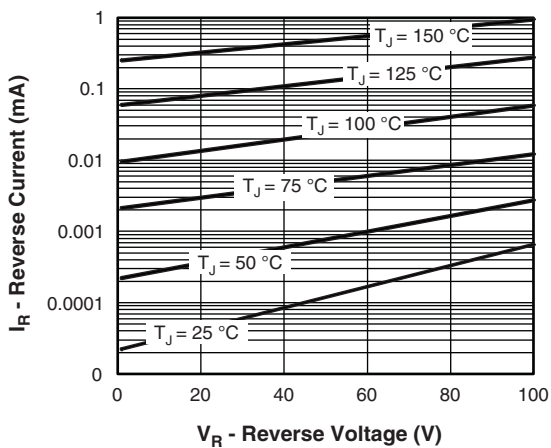


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

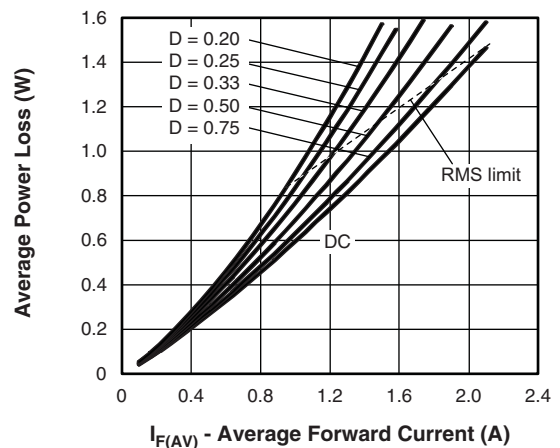


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

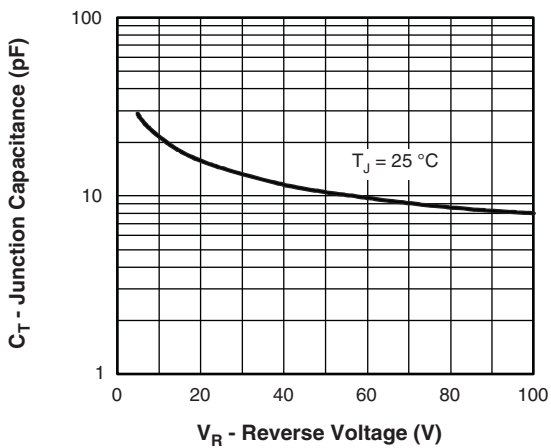


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

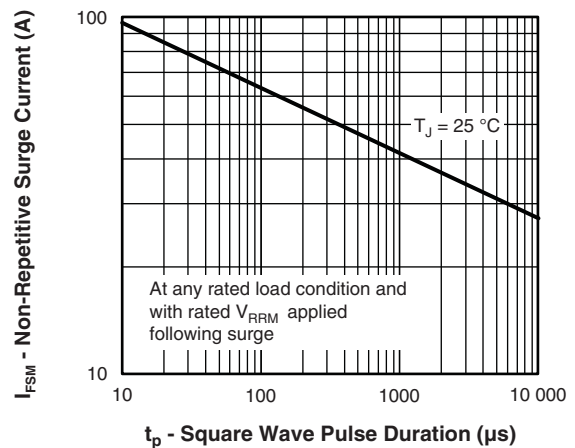


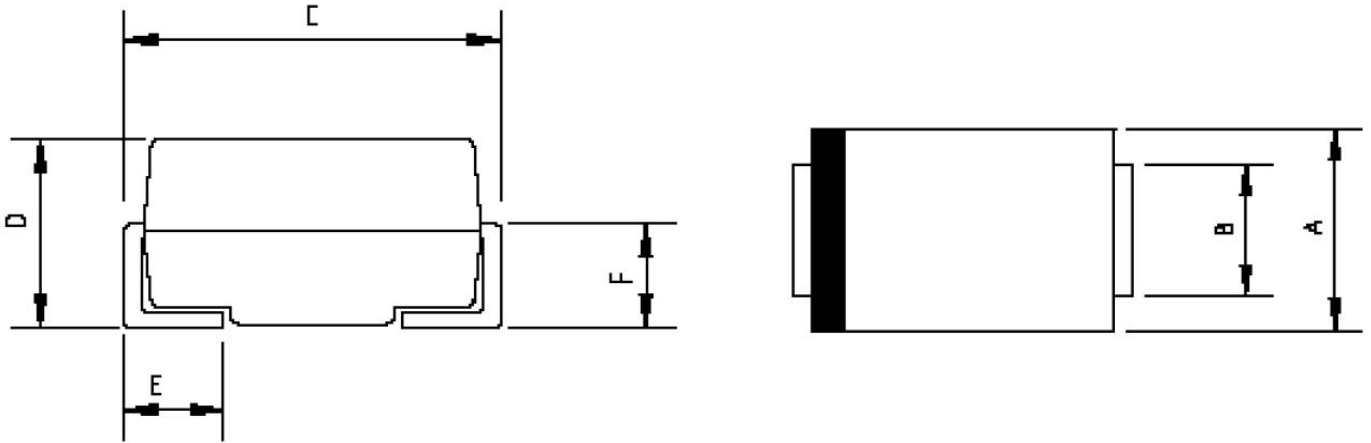
Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

- (1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  
 $Pd$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

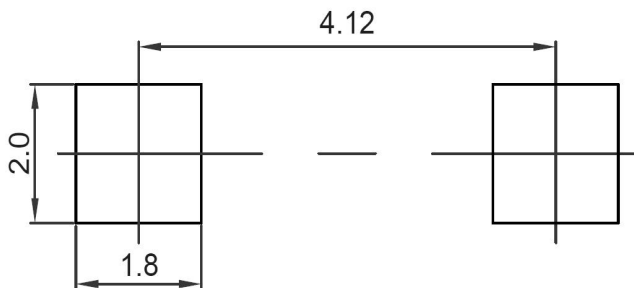
SCHOTTKY BARRIER DIODE

**SMA Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.80	0.086	0.110
B	1.30	1.70	0.051	0.067
C	4.70	5.30	0.185	0.209
D	1.70	2.55	0.067	0.100
E	0.90	1.50	0.035	0.059
F	0.90	1.50	0.035	0.059

**SMA Suggested Pad Layout**



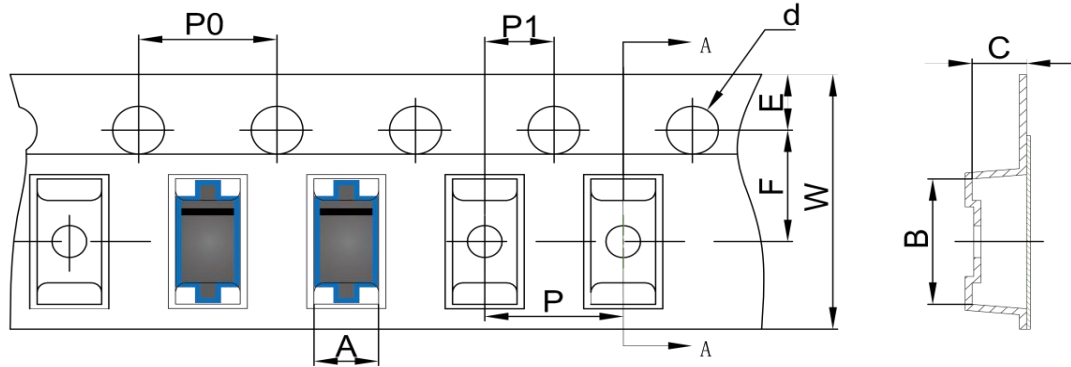
**Note:**

1. Controlling dimension: in millimeters
2. General tolerance:  $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

SCHOTTKY BARRIER DIODE

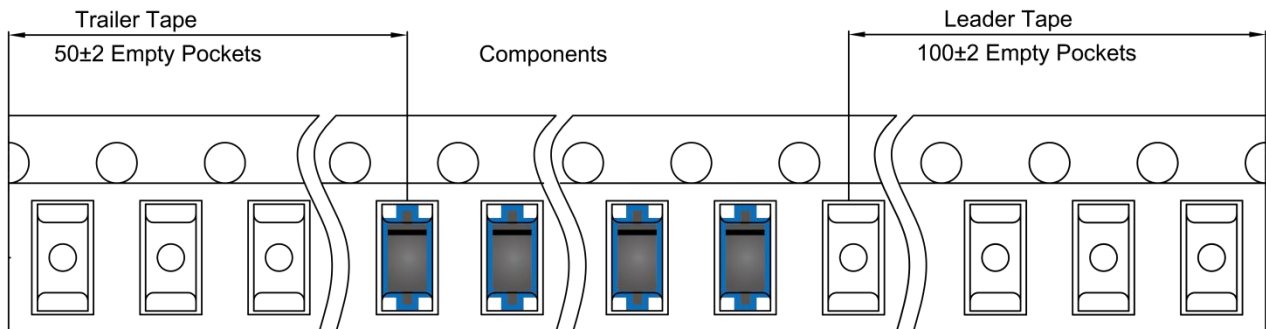
**SMA Tape and Reel**

**SMA Embossed Carrier Tape**

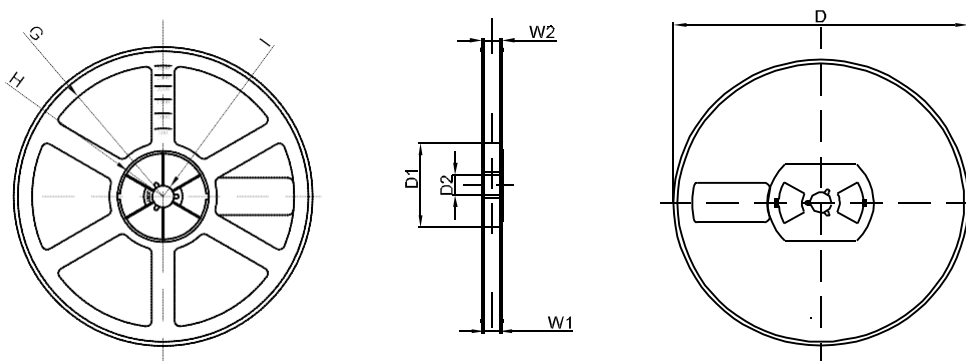


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SMA	2.89	5.35	2.68	Ø1.50	1.75	5.50	4.00	4.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

**SMA Tape Leader and Trailer**



**SMA Reel**



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	12.40	17.60
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1